

## Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	$I_D$
270V	80mΩ@10V	40A

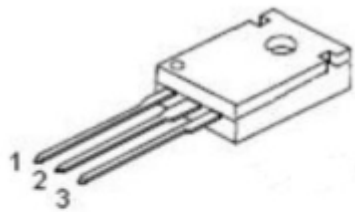
## Feature

- Fast Switching
- Low Gate Charge and Rdson
- 100% Single Pulse avalanche energy Test

## Application

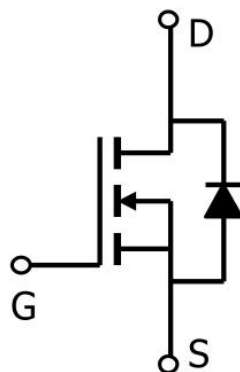
- DC-DC Converter
- Ideal for high-frequency switching and synchronous rectification

## Package

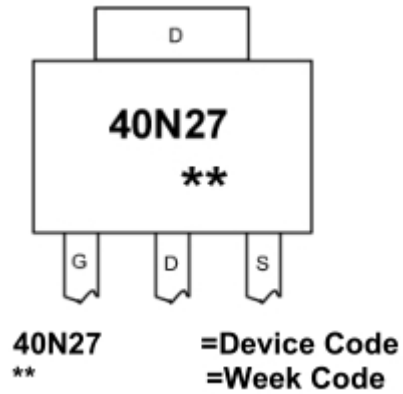


TO-247(1:G 2:D 3:S)

## Circuit diagram



## Marking



## Absolute maximum ratings

(T<sub>a</sub>=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	270	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current <sup>1</sup> (T <sub>C</sub> =25°C)	I <sub>D</sub>	40	A
Pulsed Drain Current <sup>2</sup>	I <sub>DM</sub>	160	A
Single Pulse Avalanche Energy <sup>3</sup>	E <sub>AS</sub>	1049	A
Total Power Dissipation(T <sub>C</sub> =25°C)	P <sub>D</sub>	190	W
Thermal Resistance Junction-Case <sup>1</sup>	R <sub>θJC</sub>	0.65	°C/ W
Storage Temperature Range	T <sub>STG</sub>	-55 to 150	°C
Operating Junction Temperature Range	T <sub>J</sub>	-55 to 150	°C

## Electrical characteristics

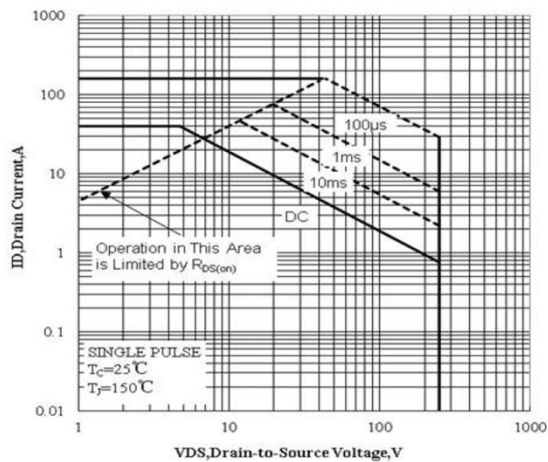
( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV (BR)DSS	V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA	270			V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =200V,V <sub>GS</sub> = 0V , T <sub>J</sub> =25°C			1	uA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V , V <sub>DS</sub> =0V			±0.1	uA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2	3	4	V
Static Drain-Source on-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =22.5A		80	100	mΩ
Dynamic Characteristics						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHz		2516		pF
Output Capacitance	C <sub>oss</sub>			338		
Reverse Transfer Capacitance	C <sub>rss</sub>			23		
Switching Characteristics						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =200V, V <sub>GS</sub> =10V, I <sub>D</sub> =40A		46		pF
Gate-Source Charge	Q <sub>gs</sub>			17		
Gate-Drain Charge	Q <sub>gd</sub>			20		
Turn-On Delay Time	T <sub>d(on)</sub>	V <sub>DS</sub> =125V, V <sub>GS</sub> =10V, R <sub>G</sub> =10Ω, I <sub>D</sub> =40A		31		nS
Rise Time	T <sub>r</sub>			152		
Turn-Off Delay Time	T <sub>d(off)</sub>			49		
Fall Time	T <sub>f</sub>			20		

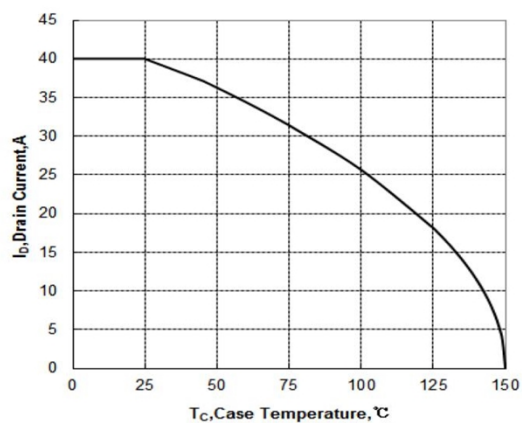
### Note:

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
2. The data tested by pulsed , pulse width  $\leq 300\mu s$  , duty cycle  $\leq 2\%$
3. The EAS data shows Max. rating . The test condition is  $R_G = 30\Omega, L = 10\text{mH}$

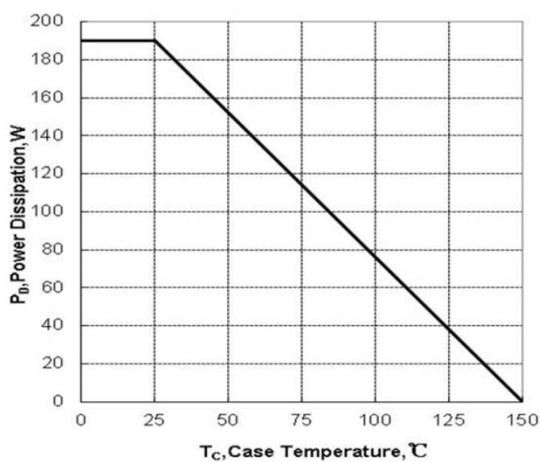
## Typical Characteristics



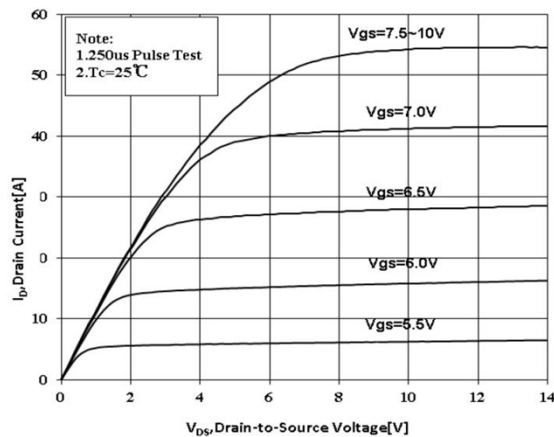
Maximum Forward Bias Safe Operating Area



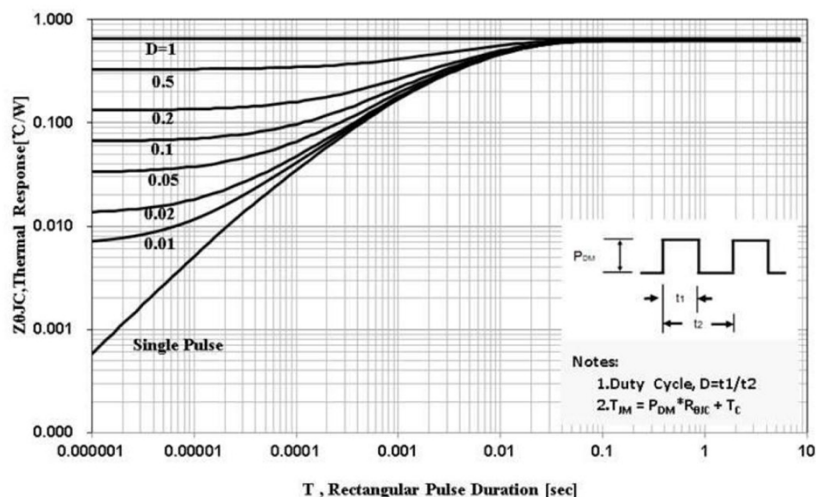
Maximum Continuous Drain Current vs Case Temperature



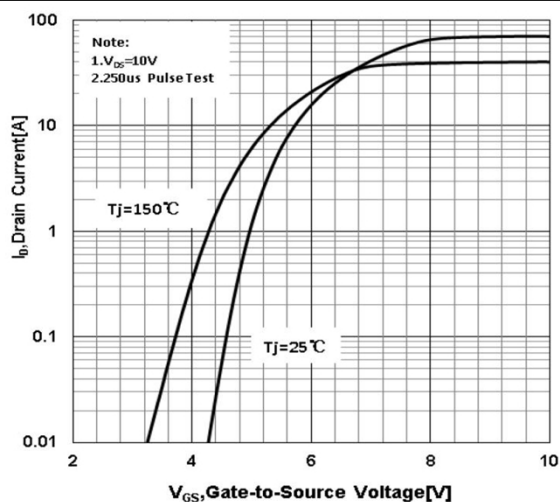
Maximum Power dissipation vs Case Temperature



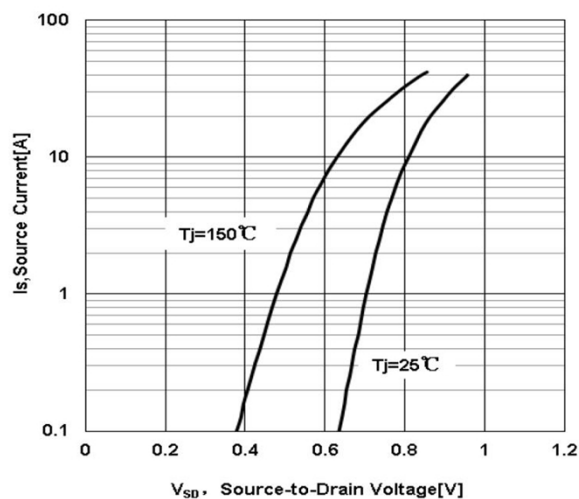
Typical Output Characteristics



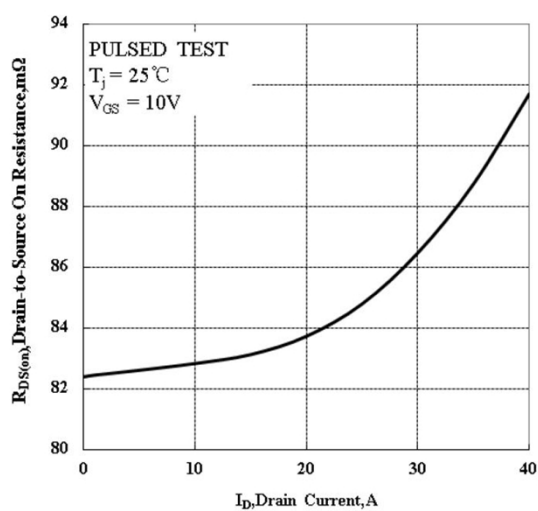
Maximum Effective Thermal Impedance, Junction to Case



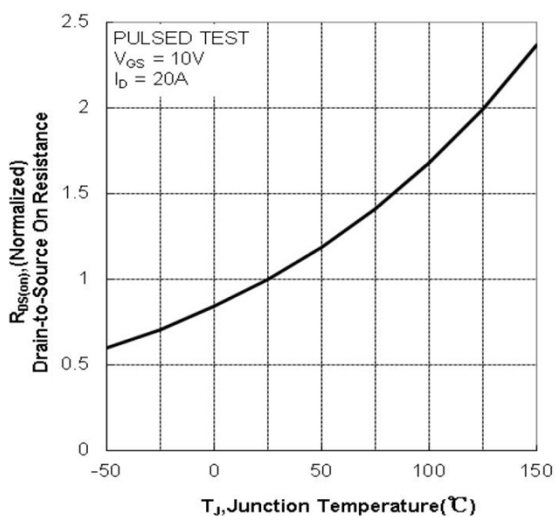
Typical Transfer Characteristics



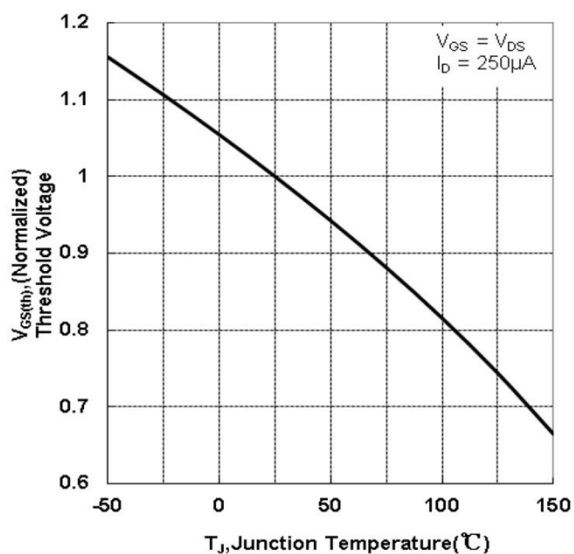
Typical Body Diode Transfer Characteristics



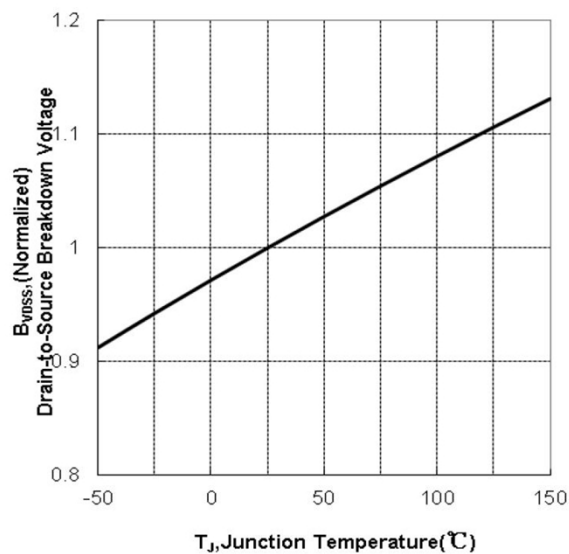
Typical Drain to Source ON Resistance  
vs Drain Current



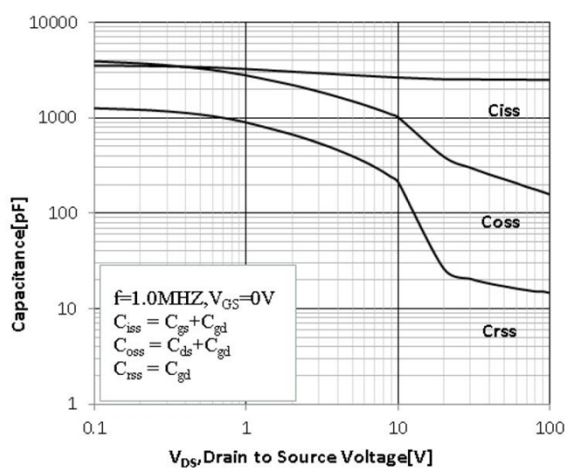
Typical Drain to Source on Resistance  
vs Junction Temperature



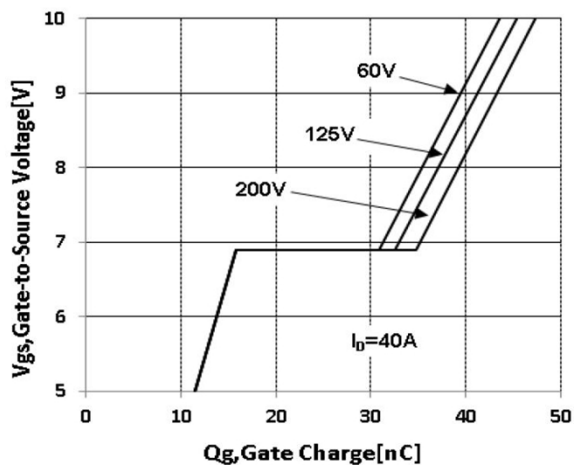
Typical Theshold Voltage vs Junction  
Temperature



Typical Breakdown Voltage vs Junction  
Temperature

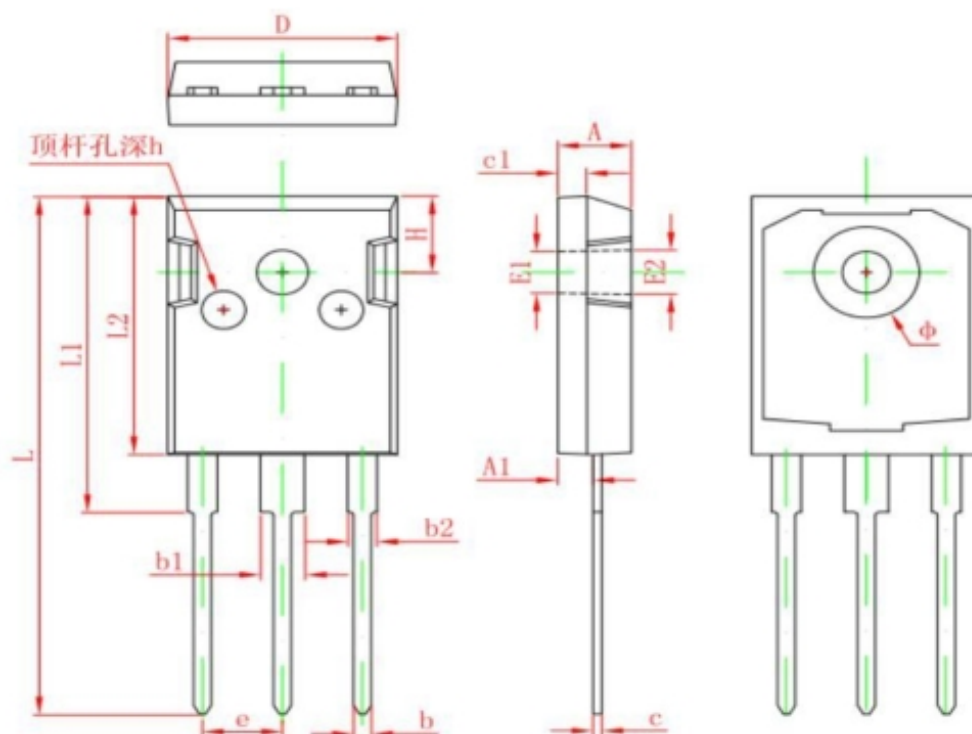


Typical Capacitance vs Drain to Source Voltage



Typical Gate Charge vs Gate to Source Voltage

## TO-247 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 REF.		0.138 REF.	
E2	3.600 REF.		0.142 REF.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
e	7.100	7.300	0.280	0.287
e	5.450 TYP.		0.215 TYP.	
H	5.980 REF.		0.235 REF.	
h	0.000	0.300	0.000	0.012